





#### **4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY**

#### **Product Summary**

V <sub>BR (Min)</sub>	I <sub>PP (Max)</sub>	Сио (тур)
5.5V	3.5A	0.45pF

### **Description**

The D5V0FS4U10LP is a high-performance device suitable for protecting four high speed I/Os. These devices are assembled in U-DFN2510-10 package and have high ESD surge capability, low ESD clamping voltage and ultra-low capacitance.

### **Applications**

Typically used at high-speed ports such as USB 3.0, USB 3.1, Serial ATA, Display port.

#### **Features**

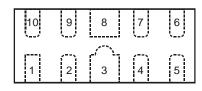
- Clamping Voltage: 6V at 16A TLP
- IEC 61000-4-2 (ESD): Air ±8kV, Contact ±8kV
- IEC 61000-4-5 (Lightning): 3.5A (8/20µs)
- 4 Channels of ESD Protection
- Ultra-Low Channel Input Capacitance of 0.45pF Typical
- TLP Dynamic Resistance: 0.25Ω
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

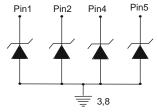
- Case: U-DFN2510-10
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper Leadframe (Lead Free Plating).
   Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.038 grams (Approximate)

#### U-DFN2510-10

Pin#	Description
1, 2, 4, 5	I/O
6, 7, 9, 10	No Connection
3, 8	Vss



Pin Description (Top View)



**Device Schematic** 

### Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity
D5V0FS4U10LP-7	Standard	NZ1	7	8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# Marking Information

U-DFN2510-10

NZ1 YM

NZ1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Key

Year	2017	2018	2019	2020	2021	2022
Code	Е	F	G	Н		J

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current, per IEC 61000-4-5	IPP	3.5	Α	I/O to V <sub>SS</sub> , 8/20µs
Peak Pulse Power, per IEC 61000-4-5	$P_PP$	20	W	I/O to V <sub>SS</sub> , 8/20µs
ESD Protection – Contact Discharge, per IEC 61000-4-2	V <sub>ESD_CONTACT</sub>	±8	kV	I/O to V <sub>SS</sub>
ESD Protection – Air Discharge, per IEC 61000-4-2	V <sub>ESD_AIR</sub>	±8	kV	I/O to V <sub>SS</sub>

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	$P_{D}$	350	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	$R_{ hetaJA}$	360	°C/W
Operating and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 to +150	°C

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Working Voltage	$V_{RWM}$	_	_	5	V	_
Reverse Current	I <sub>R</sub>	_	_	1	μA	$V_R = 5V$ , I/O to $V_{SS}$
Reverse Breakdown Voltage	$V_{BR}$	5.5	7.0	_	V	I <sub>R</sub> = 1mA, I/O to V <sub>SS</sub>
Forward Clamping Voltage	V <sub>F</sub>	-1.0	-0.85	_	V	$I_F = -15$ mA, I/O to $V_{SS}$
Holding Reverse Voltage	$V_{HOLD}$	_	1.19	_	V	I/O to V <sub>SS</sub>
Holding Reverse Current	I <sub>HOLD</sub>	_	90	_	mA	I/O to V <sub>SS</sub>
Reverse Clamping Voltage (Note 6)	Vc	_	3	_	V	$I_{PP} = 3A$ , I/O to $V_{SS}$ , 8/20µs
Clamping Voltage (Note 7)	$V_{C}$	_	6	_	V	TLP, 16A, tp = 100ns, I/O to $V_{SS}$
Clamping Voltage (Note 7)	Vc	_	4.5	_	V	TLP, -16A, tp = 100ns, I/O to $V_{SS}$
Dynamic Reverse Resistance	R <sub>DIF-R</sub>	_	0.25	_	Ω	TLP, 10A, tp = 100ns, I/O to $V_{SS}$
Dynamic Forward Resistance	R <sub>DIF-F</sub>	_	0.2	_	Ω	TLP, 10A, tp = 100ns, V <sub>SS</sub> to I/O
Channel Input Capacitance	C <sub>I/O</sub>	_	0.45	_	pF	$V_{I/O} = 0V$ , $V_{SS} = 0V$ , $f = 1MHz$

Notes:

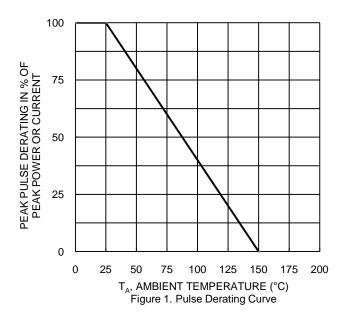
<sup>5.</sup> Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.

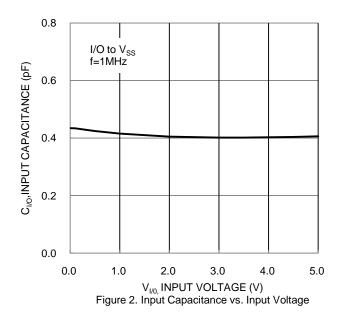
 $<sup>\</sup>dot{\text{6}}$  . Clamping voltage value is based on an 8x20µs peak pulse current (Ipp) waveform.

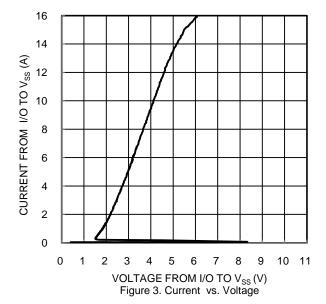
<sup>7.</sup> Clamping voltage value is based on an TLP model. TLP conditions: Z<sub>0</sub>=50Ω, tp = 100ns, averaging window; t1=70ns to t2=90ns.











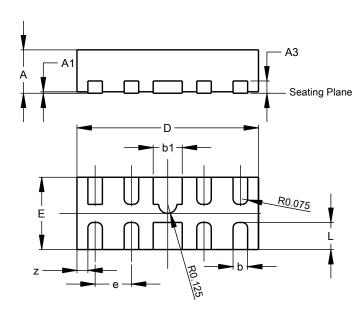
D5V0FS4U10LP Document number: DS39520 Rev. 1 – 2



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2510-10

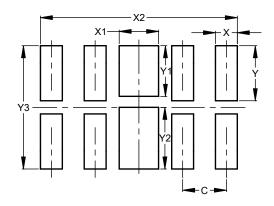


U-DFN2510-10							
Dim	Min	Max	Тур				
Α	0.545	0.605	0.575				
A1	0.00	0.05	0.03				
А3	-	-	0.13				
b	0.15	0.25	0.20				
b1	0.35	0.45	0.40				
D	2.450	2.575	2.500				
е	-	-	0.50				
Е	0.950	1.075	1.000				
L	0.325	0.425	0.375				
Z	-	-	0.150				
All D	All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2510-10



Dimensions	Value (in mm)
С	0.500
Х	0.250
X1	0.450
X2	2.250
Y	0.625
Y1	0.575
Y2	0.700
Y3	1.400



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